

Crystal Growth: Physics, Technology and Modeling

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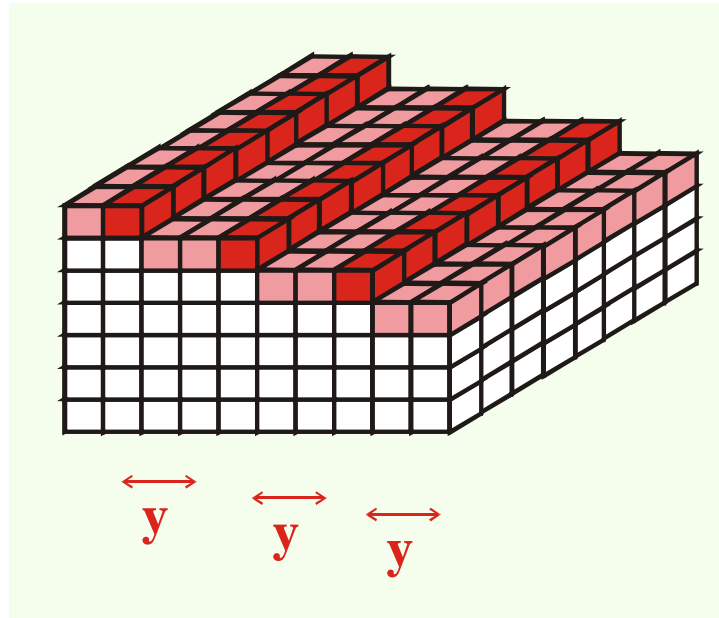
Lecture 7. Step motion

<http://w3.unipress.waw.pl/~stach/cg-2022-23/>

Scope

- **Vicinal surface - step trains**
- **Step meandering**
- **Step bunching**
- **Double steps**
- **Macro steps**
- **Mounds & Islands**

Vicinal surface – step trains

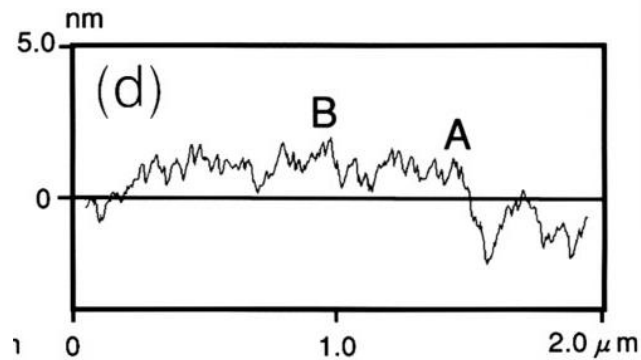
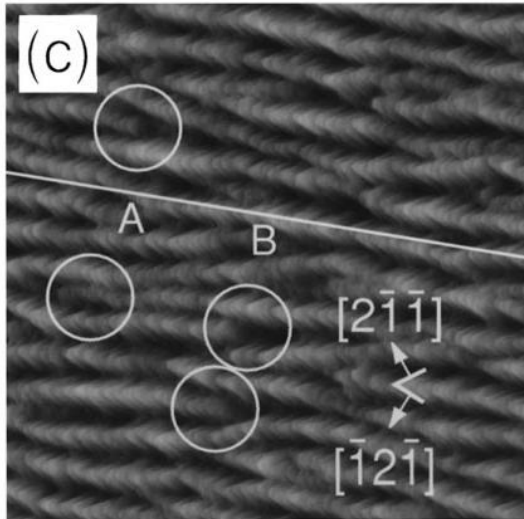


Misorientation

$$a = y \operatorname{tg}(\alpha) \quad \longrightarrow \quad \alpha = \operatorname{atan}\left(\frac{a}{y}\right)$$

Step instabilities - meandering

- Si(111) surface deposition



*H. Omi, T. Ogino, Thin Solid Films
380 (2000) 15*

- GaN(0001) - MOVPE



AFM – G. Nowak

*S. Krukowski et al. Cryst. Res. Technol.
42 (2007) 1281*

Step fluctuations - equilibrium

- **Drumhead – elastic model**

$$F = \int dx \left[\frac{G}{2} \left(\frac{\partial z}{\partial x} \right)^2 + U z^2 \right] = \sum_k \left[\frac{G k^2}{2} + U \right] z_k^2$$

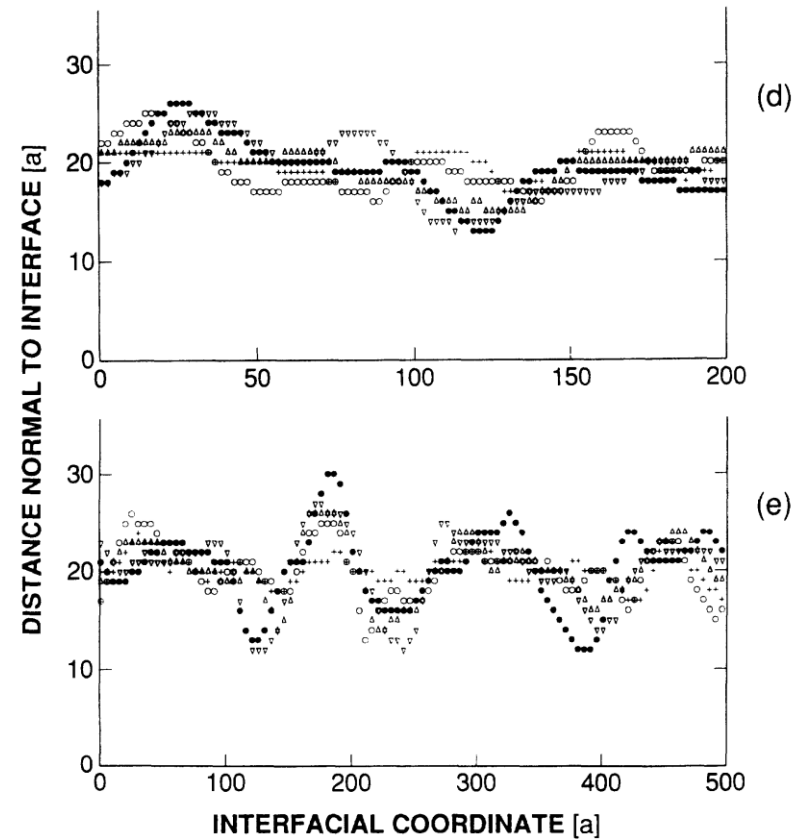
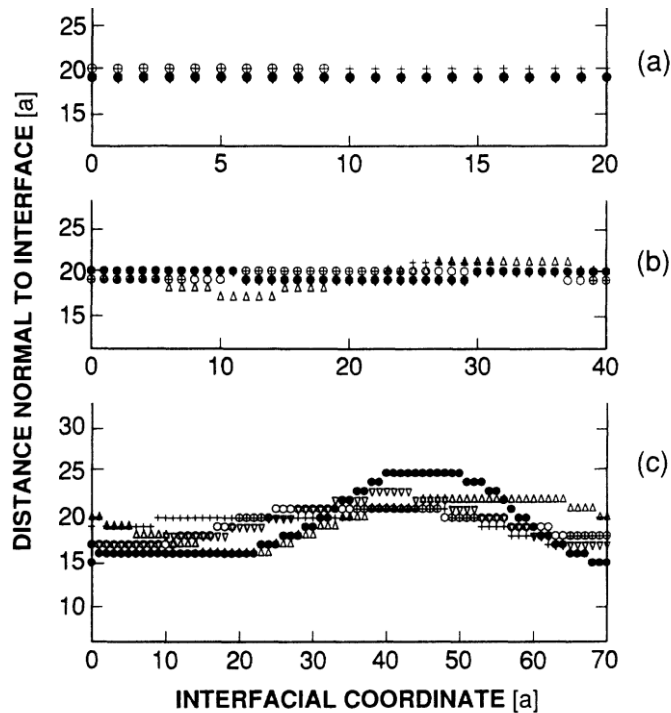
z – deviation from the straight line (z = 0)

- **Average width**

$$\langle z^2 \rangle = \frac{\int dz z^2 \exp(-F/kT)}{\int dz \exp(-F/kT)} \cong \int \frac{2\pi k}{Gk^2 + 2U} dk$$

$$\langle z^2 \rangle \cong \pi \ln \left(\frac{G}{2} \left(\frac{\pi}{2L} \right)^2 + U \right) = 2 \lim_{L \rightarrow \infty, U \rightarrow 0} \ln(L) = \infty$$

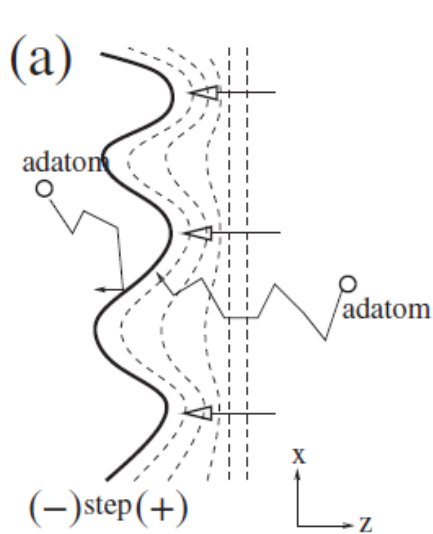
Step fluctuations - Monte Carlo equilibrium simulations



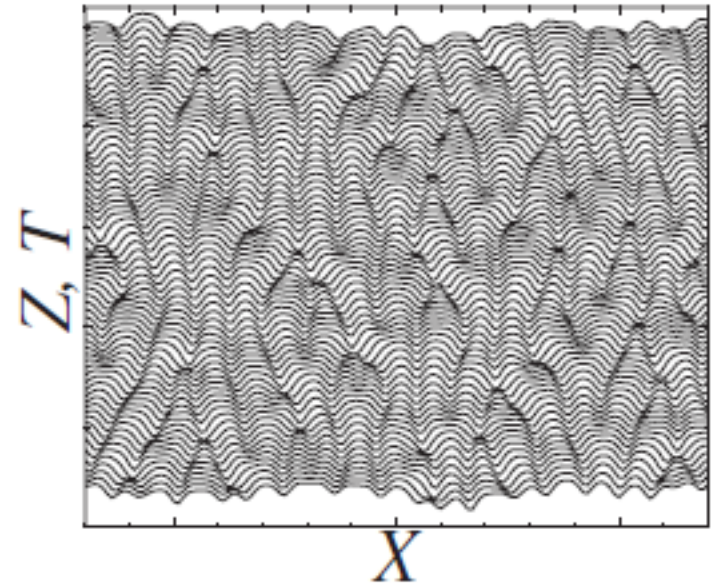
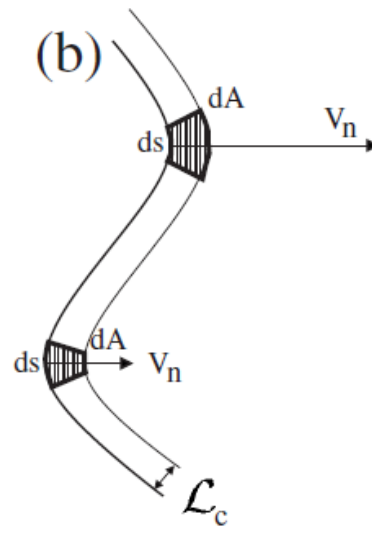
***S. Krukowski, F. Rosenberger,
Phys. Rev. B 49 (1994) 12 464***

Step meandering mechanism

- Ehrlich-Schwoebel effect



- K-S instability

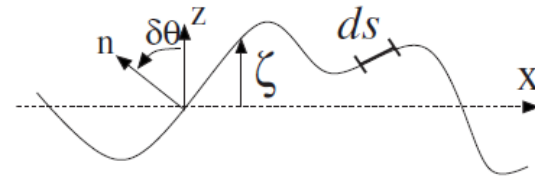


C. Misbah, O. Pierre-Luis, Y. Saito Rev. Mod. Phys. 82(2010) 981

Step fluctuations in nonequilibrium - Kuramoto-Sivashinski equation

- Deviation from straight step - $\zeta = \zeta(x, t)$ in BCF solution

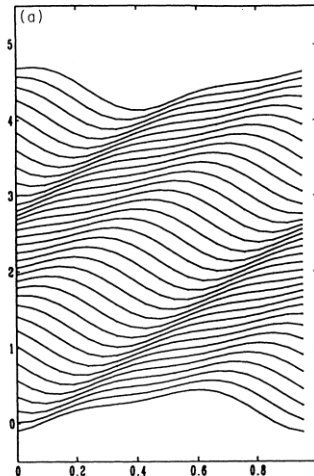
$$\frac{\partial \zeta}{\partial t} = -a \frac{\partial^2 \zeta}{\partial x^2} - b \frac{\partial^4 \zeta}{\partial x^4} + v \left(\frac{\partial \zeta}{\partial x} \right)^2$$



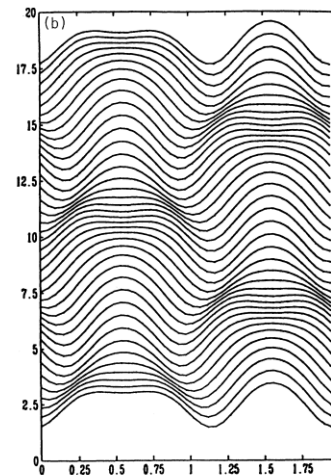
Lyapunov stability

$$\zeta = \zeta_0 \exp(\lambda t - ikx) \quad \lambda = ak^2 - bk^4 + f(k) = \begin{cases} > 0 & \text{unstable} \\ < 0 & \text{stable} \end{cases}$$

**Broken parity
travelling mode**



**Vacillating-
breathing mode**

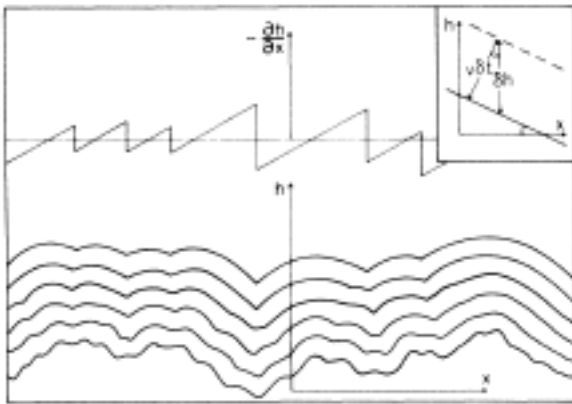


Step fluctuations in nonequilibrium – Kardar-Parisi-Zhang (KPZ) equation

- **Deviation from straight step - $h = h(x, t)$**

$$\frac{\partial h}{\partial t} = v \frac{\partial^2 h}{\partial x^2} + \frac{\lambda}{2} \left(\frac{\partial h}{\partial x} \right)^2 + \eta(x, t)$$

$\eta(x, t)$ - random force

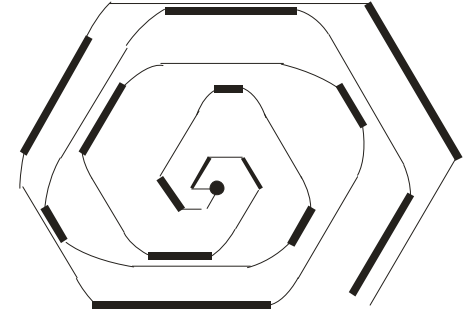
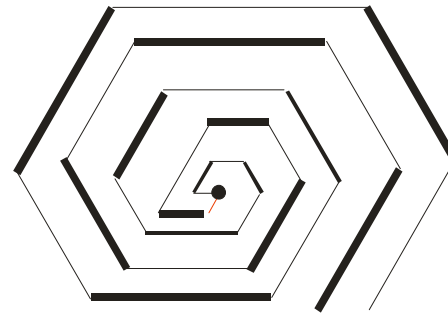
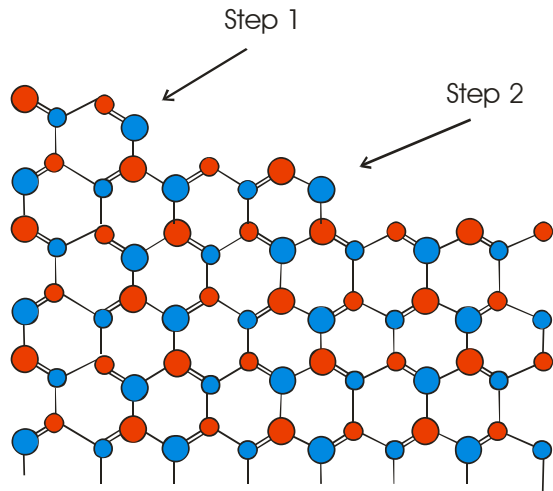


Successive profiles obtained from KPZ equation

Inset – perpendicular growth mechanism

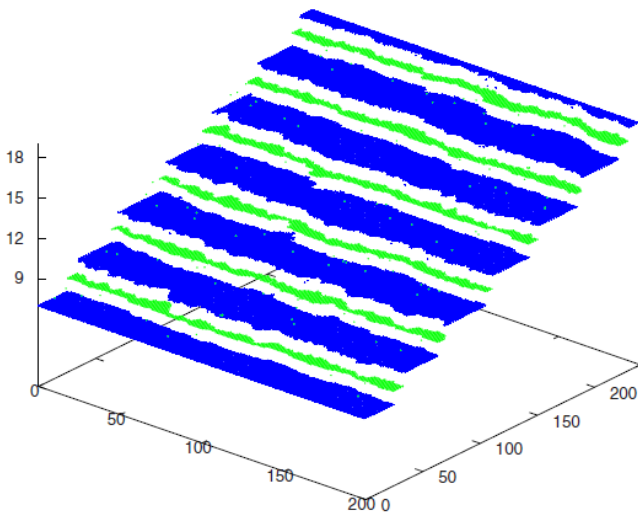
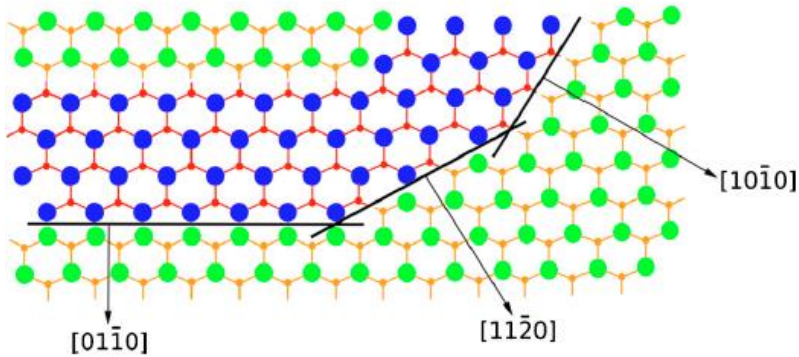
***M. Kardar, G. Parisi, Y-C. Zhang
Phys. Rev. Lett. 56 (1986) 889***

Step difference related meandering mechanism

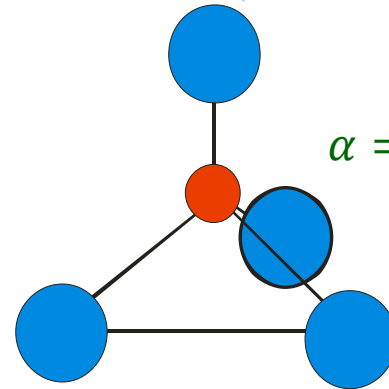
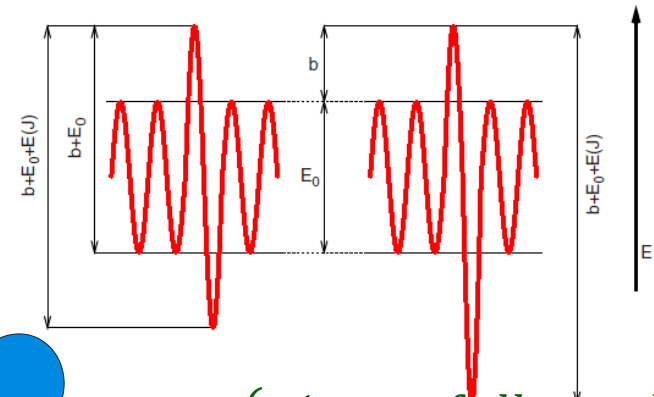


Monte Carlo simulation of surface diffusion – GaN(0001) surface

- Step structures



- Ehrlich-Schwoebel effect - E_{bar}



$$\alpha = \begin{cases} 1 & \text{full tetrahedron} \\ \frac{1}{3}rn & \text{not full tetrahedron} \end{cases}$$

$$E = \phi \sum_{i=1}^4 \alpha_i$$

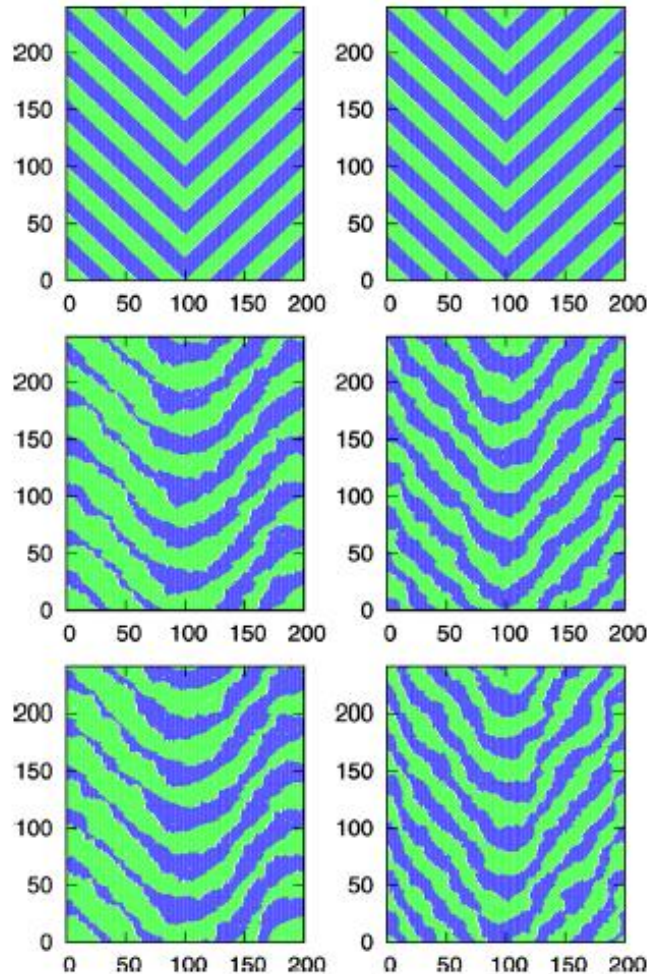
$$P = v \exp\left(-\frac{\Delta E + E_{bar}}{kT}\right)$$

M. Załuska-Kotur et al.
J. Appl. Phys. 109 (2011) 023515

MC simulation – GaN(0001) surface – difference in dynamics

$r = 0.4$

$r = 1$



$t = 0$ MC steps

$t = 5 \times 10^6$ MC steps

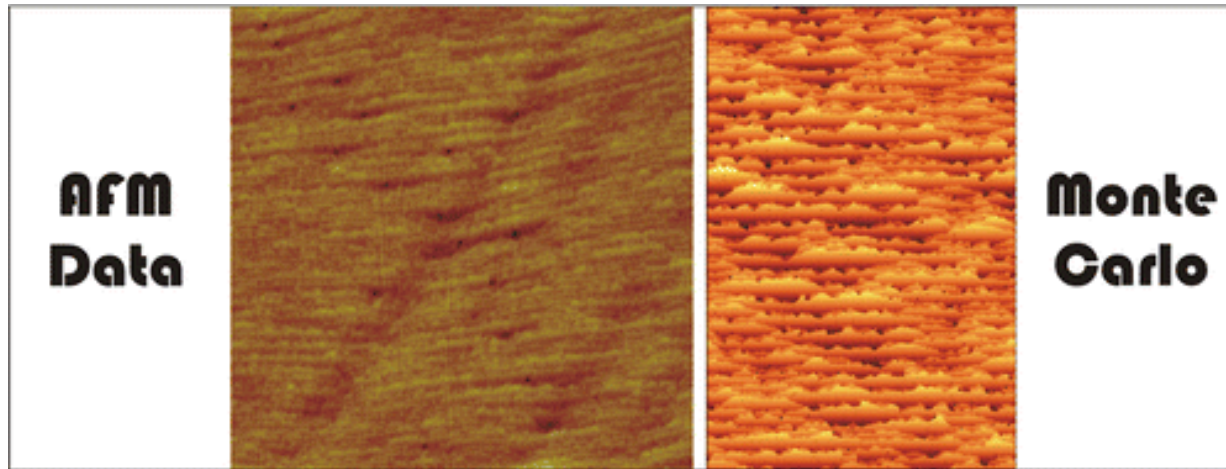
$t = 1 \times 10^7$ MC steps

M. Załuska-Kotur et al.

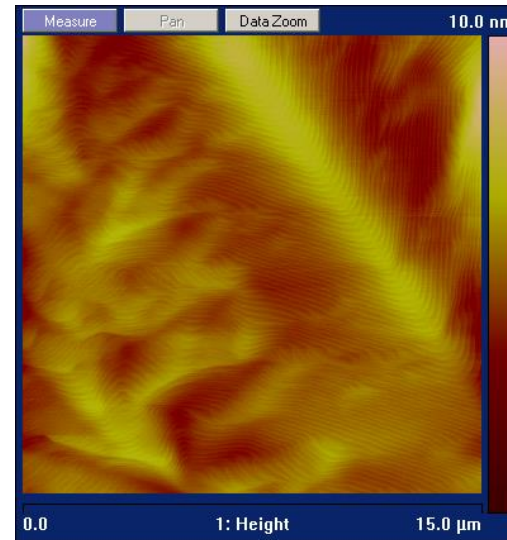
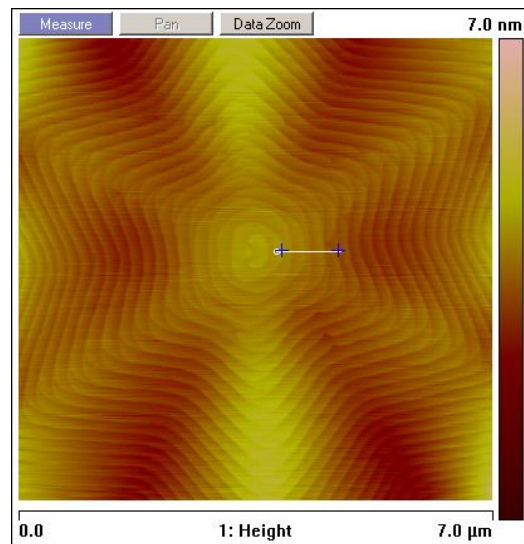
J. Appl. Phys. 109 (2011) 023515

23.11.2022 – Step motion

MOVPE growth and MC simulations of GaN(0001) surface



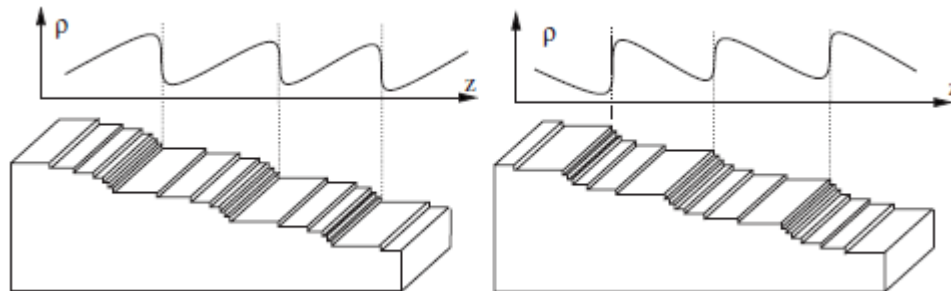
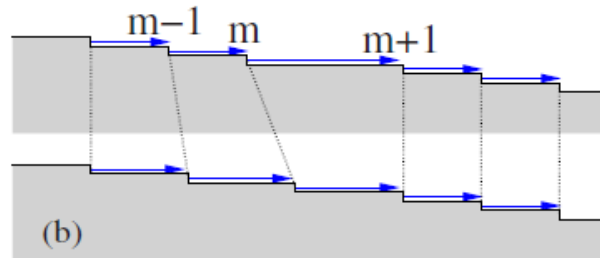
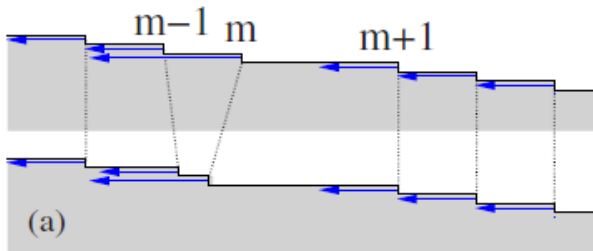
*M. Załuska-Kotur et al.
Cryst. Growth Des.
13 (2013) 1006*



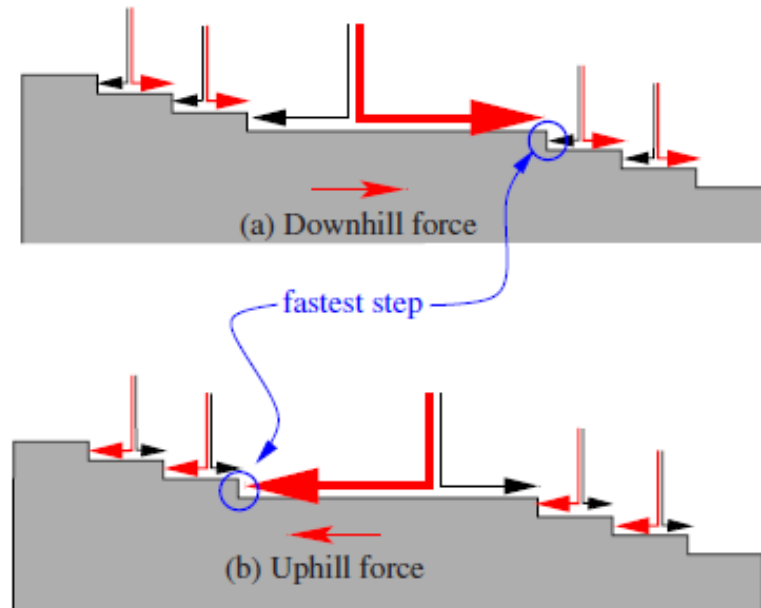
R. Czernecki, AFM data

Step bunching

- Ehrlich-Schwoebel effect

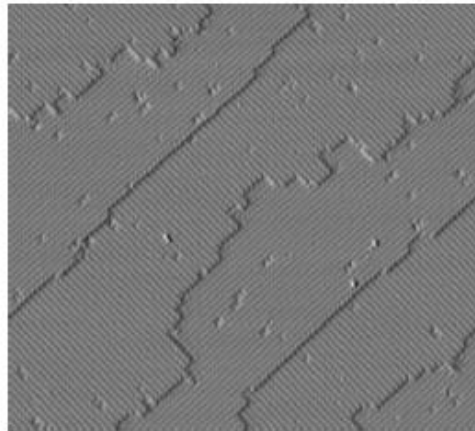


Step bunching – Si growth – instability mechanism

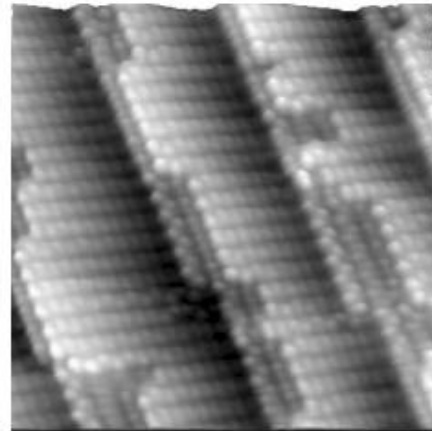


*C. Misbah, O. Pierre-Luis, Y. Saito,
Rev. Mod. Phys. 82(2010) 981*

Si growth – double steps



(a)



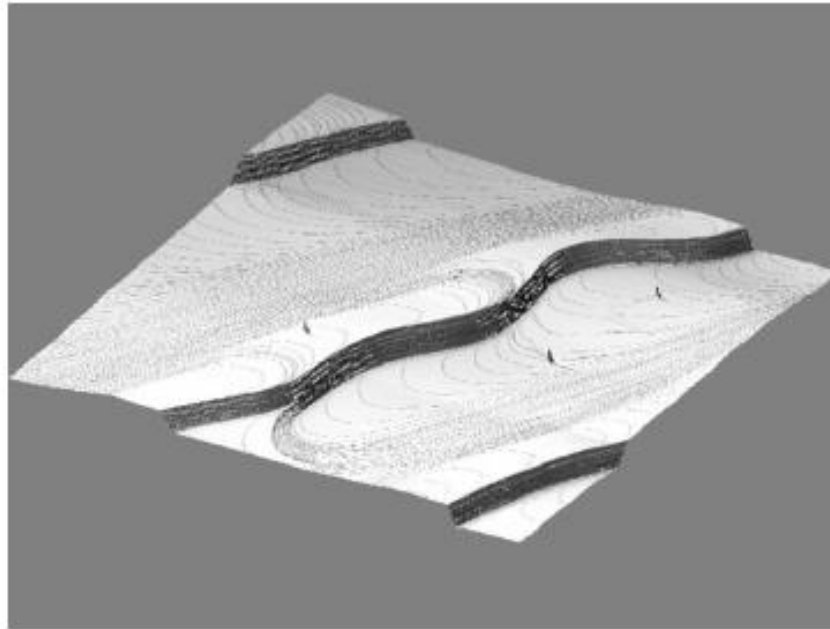
(b)

- **AFM – M. Lagally**

*C. Misbah, O. Pierre-Luis, Y. Saito,
Rev. Mod. Phys. 82(2010) 981*

Step bunching – Si growth

- **Macrosteps**
- **Single steps on terraces**



Kinetics of anisotropic steps

$$R_{\pm} = k_{\pm} v (c_{sur} - c_{sur-eq}) = \frac{k_{\pm} c_{sur-eq} \sigma}{\tau_o}$$

$$\sigma = \sigma_v \left[1 - \frac{\alpha \cosh\left(\frac{2z-y}{l_{sur}}\right)}{\cosh\left(\frac{2y}{l_{sur}}\right)} - \frac{\beta \cosh\left(\frac{2z+y}{l_{sur}}\right)}{\cosh\left(\frac{2y}{l_{sur}}\right)} \right] \quad -\frac{y}{2} < z < \frac{y}{2}$$

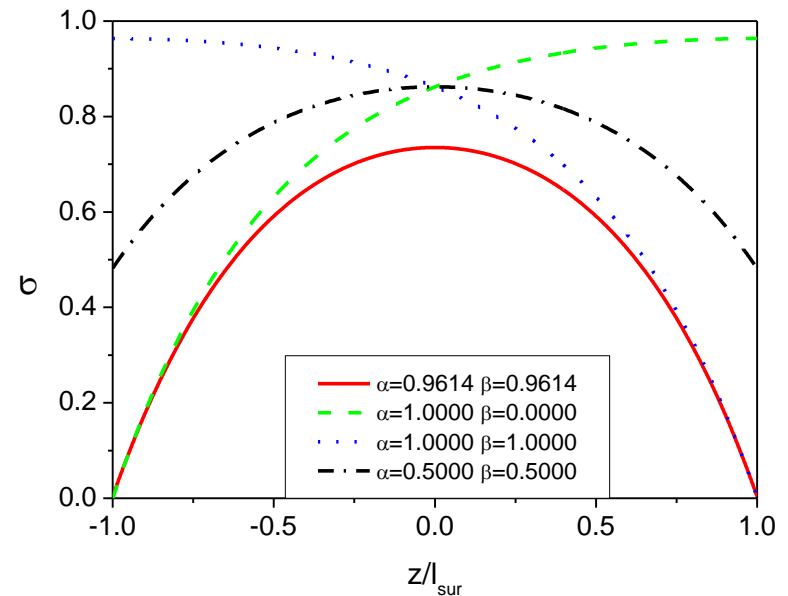
$$\alpha = \frac{g_-}{g_- + \tanh\left(\frac{y}{l_{sur}}\right)} = \frac{2k_- \tau_{sur} a}{2k_- \tau_{sur} a + l_{sur} \tau_o \tanh\left(\frac{y}{l_{sur}}\right)}$$

$$\beta = \frac{g_+}{g_+ + \tanh\left(\frac{y}{l_{sur}}\right)} = \frac{2k_+ \tau_{sur} a}{2k_+ \tau_{sur} a + l_{sur} \tau_o \tanh\left(\frac{y}{l_{sur}}\right)}$$

$$g_- = \frac{\tau_{sur} k_- a}{l_{sur}}$$

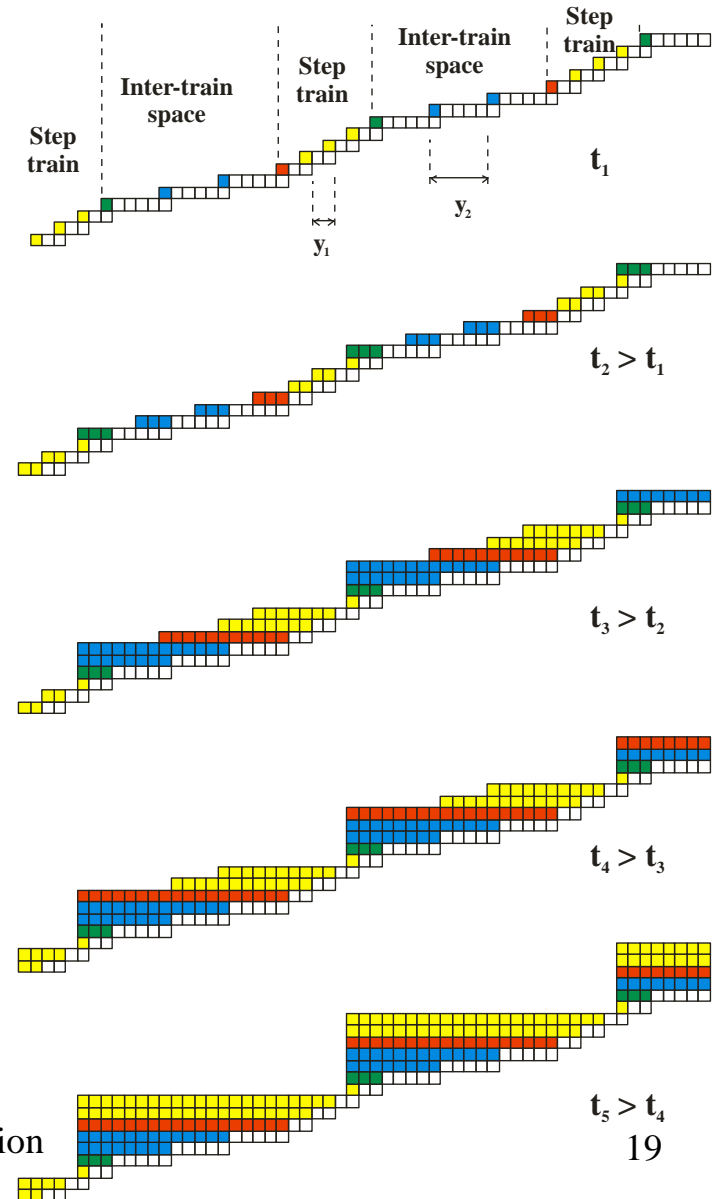
$$g_+ = \frac{\tau_{sur} k_+ a}{l_{sur}}$$

- Supersaturation at the terrace



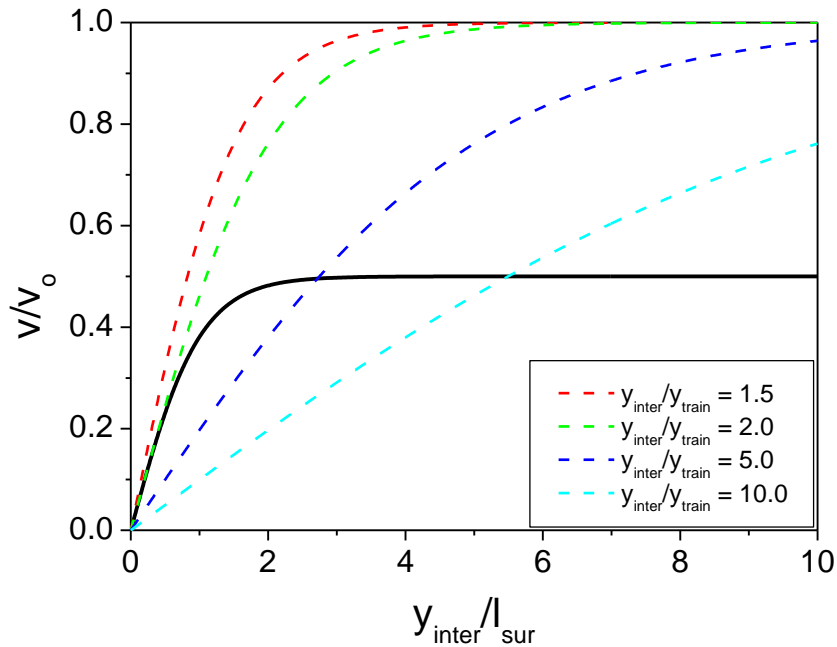
Evolution of the step train – creation of double steps

- **Nonuniform step distribution**
- **Motion of: the last step in the train & first step in the interstep**
- **Criterion: motion of single side alimented step is faster than the two-side alimented step**
- **Creation of double step**
- **Coalescence of the following steps**

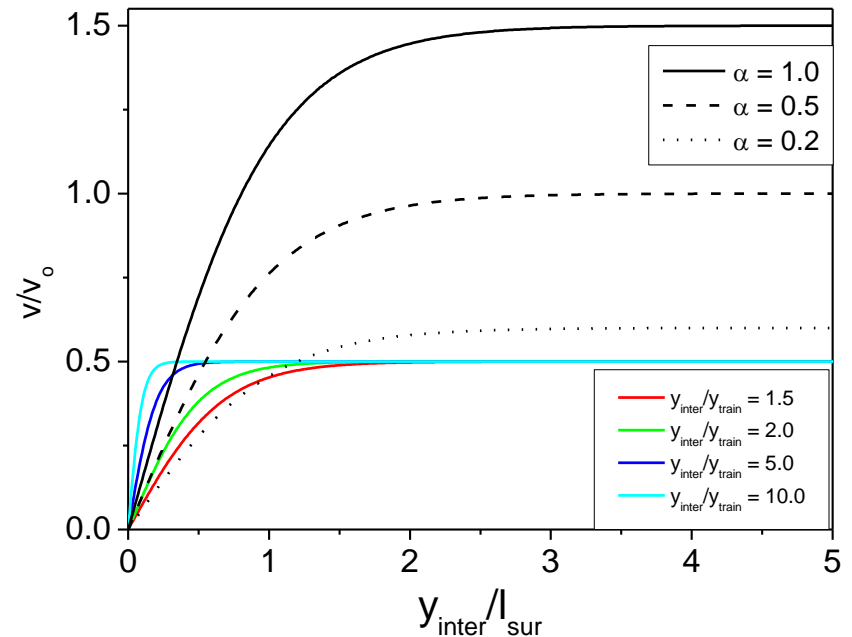


Creation of double step

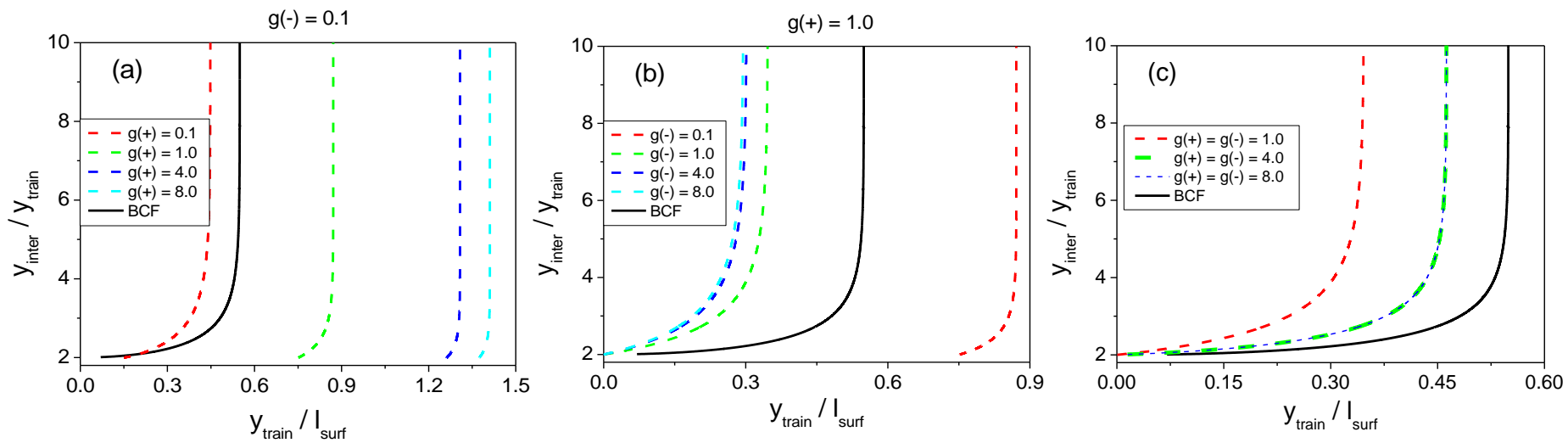
- BCF kinetics



- Symmetric kinetics



Step bunching – coalescence regions



Macrostep evolution – emission of single steps

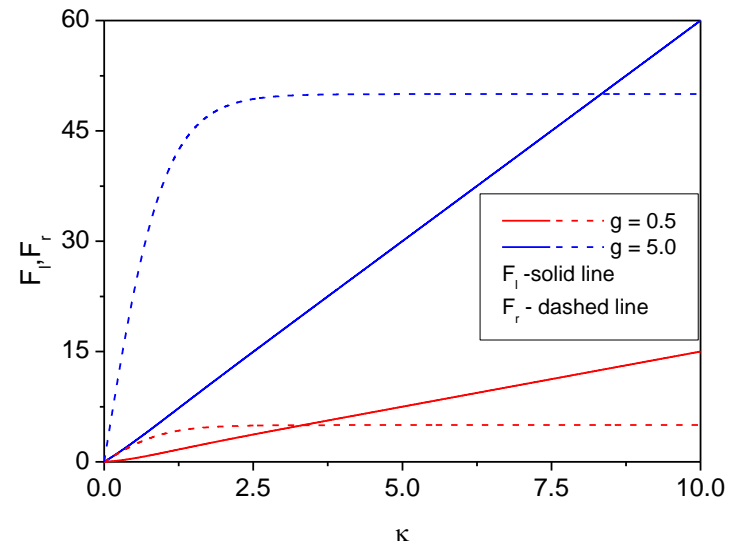
- Macrosteps – slow motion
- Single steps on superterraces – fast motion

$$z(t) = v_3 t \tanh\left(\frac{t}{t_1}\right)$$

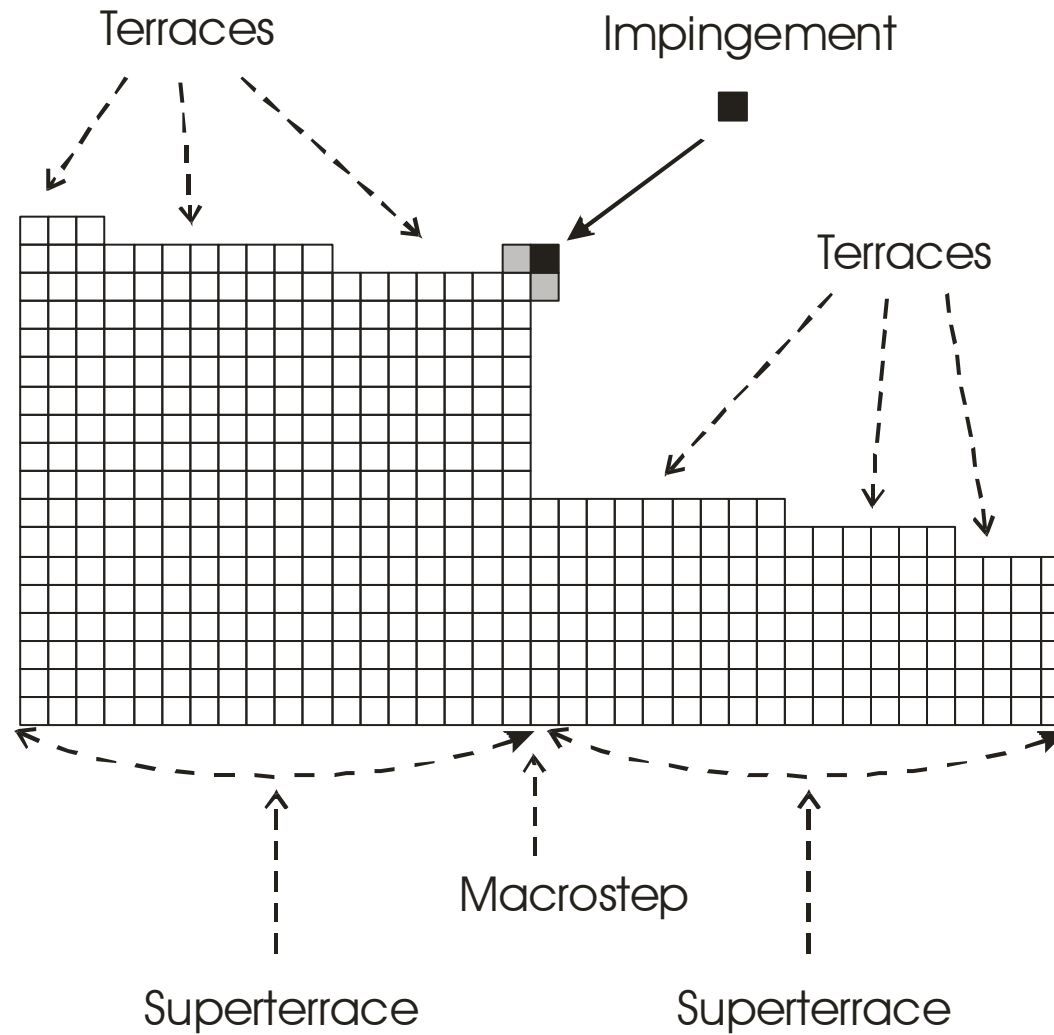
$$\kappa[g + \tanh(\kappa)] = \sigma_v c_{sur-eq} \left(\frac{t_1}{\tau_{sur}}\right) g \tanh(\kappa)$$

$$\kappa \equiv \frac{\Delta z_3}{l_{sur}} = \frac{v_3 t_1}{l_{sur}}$$

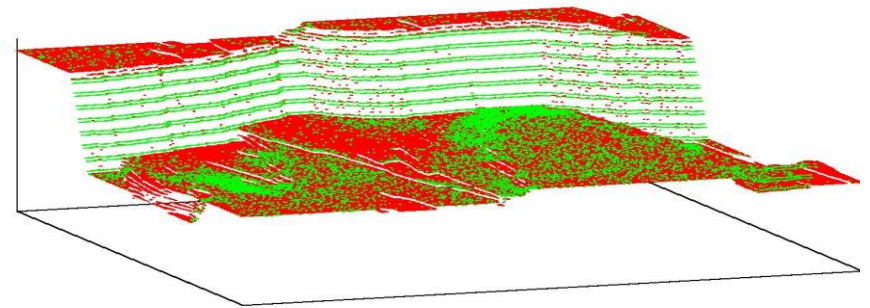
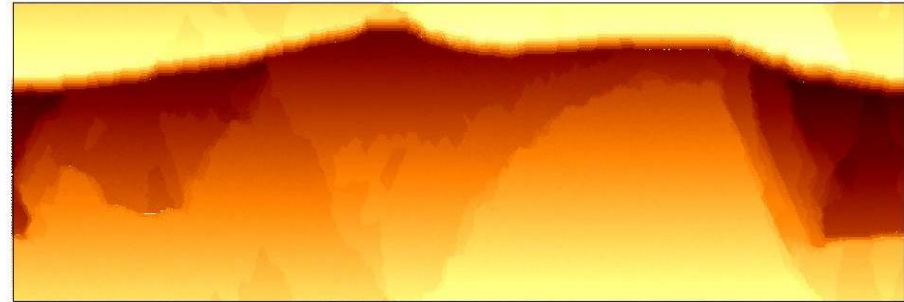
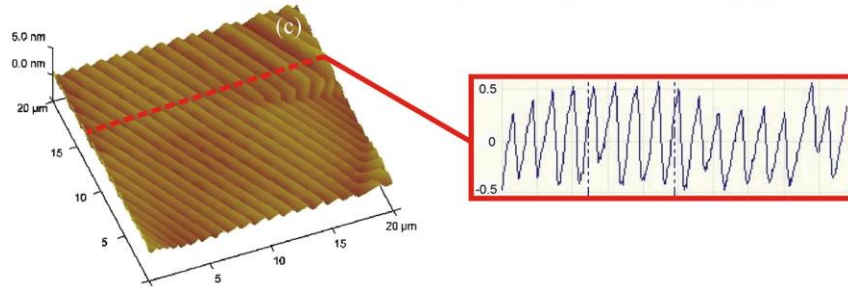
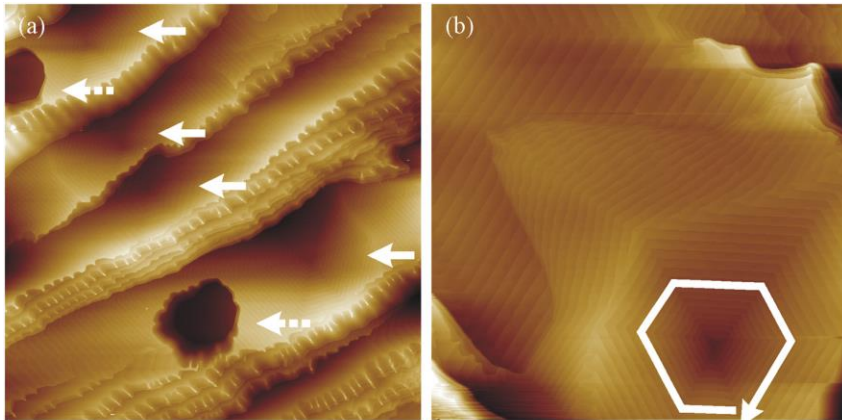
$$g = \frac{\tau_{sur} k a}{l_{sur}}$$



Surface structure – macrosteps & superterraces



Si(111) surface - annealing



J. Hassan et al., J. Cryst. Growth 310 (2008) 4430

2-d nucleation on terraces – Pt on Pt(111)

0.3 ML

3 ML

12 ML

90 ML

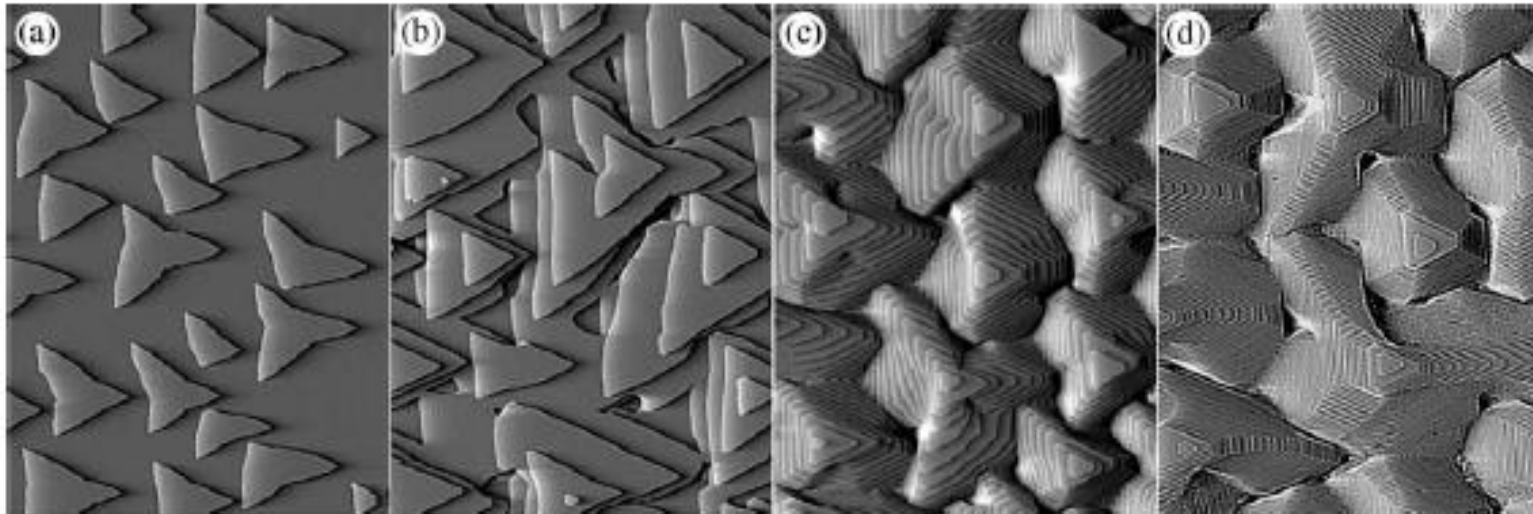


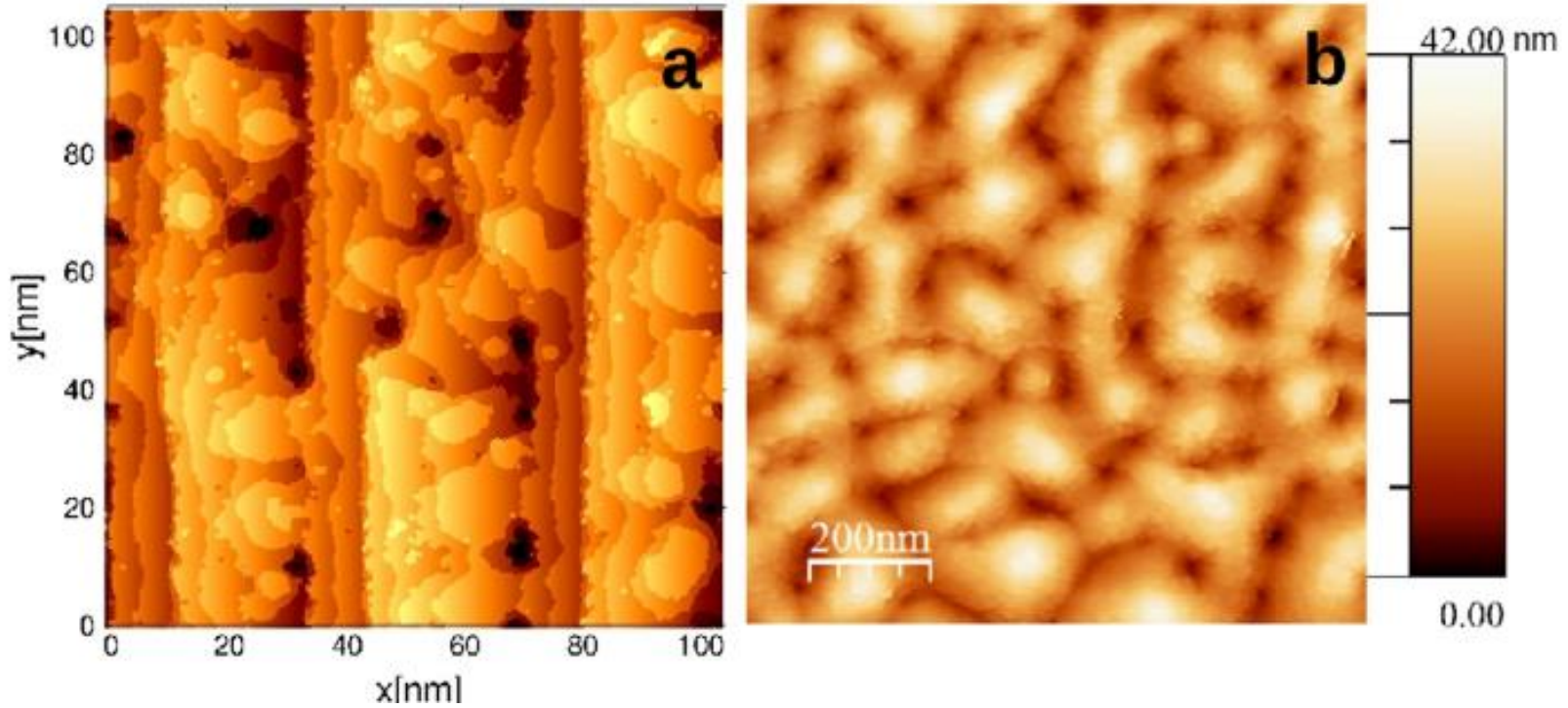
Fig. 2. Growth of Pt on Pt(111) at $T=440$ K [5]. The total coverage is (a) 0.3 monolayers (ML), (b) 3 ML, (c) 12 ML and (d) 90 ML. The image size is $2600 \text{ \AA} \times 3450 \text{ \AA}$. Courtesy of T. Michely.

J. Krug, *Physica A* 313 (2002) 47

2-d nucleation on terraces – GaN on GaN (0001)

MC simulation

MBE growth



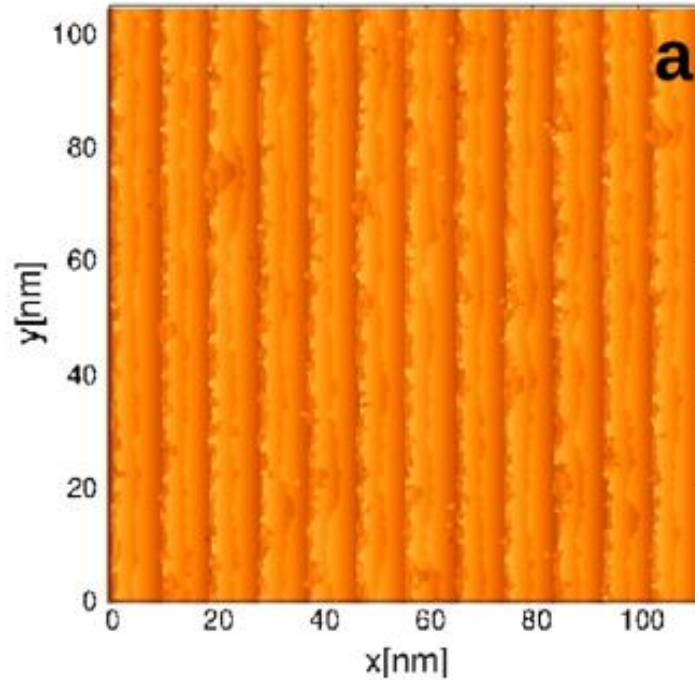
$\alpha = 2 \text{ arc deg}$

$T = 750 \text{ }^\circ\text{C}$

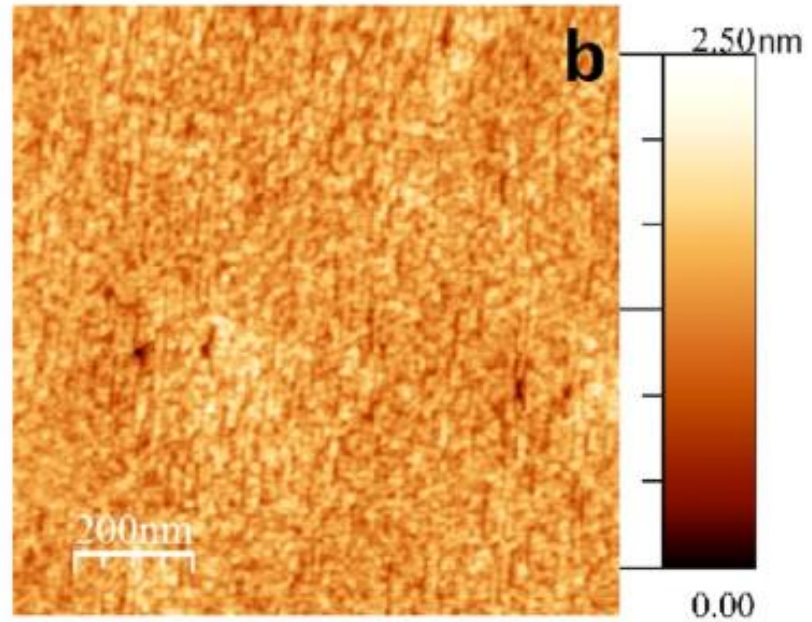
F. Krzyzewski et al., J. Cryst. Growth 457 (2017) 38

2-d nucleation on terraces – GaN on GaN (0001)

MC simulation



MBE growth



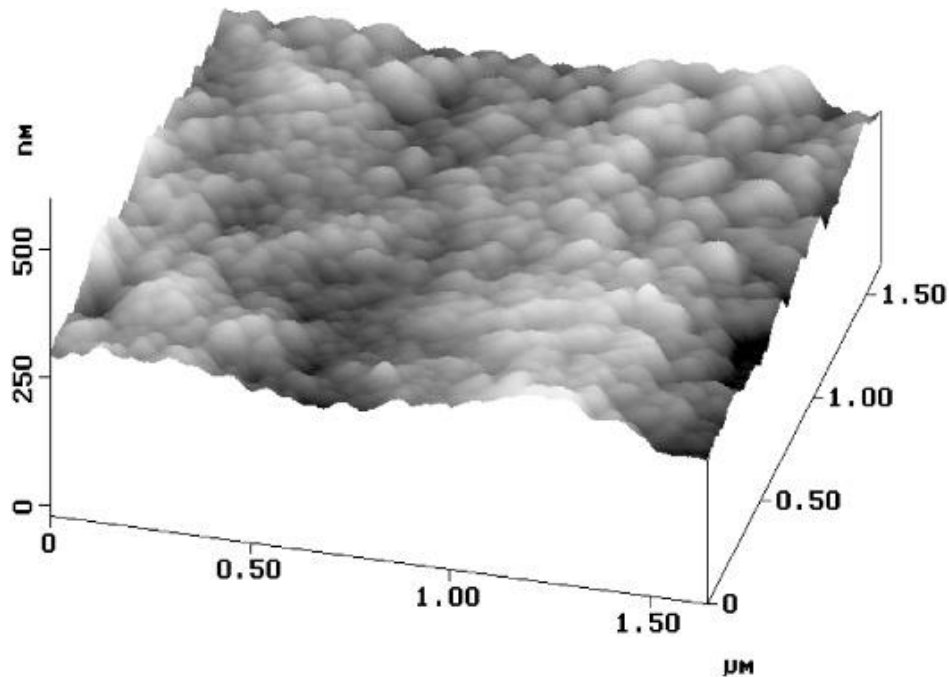
$\alpha = 4 \text{ arc deg}$

$T = 750 \text{ }^\circ\text{C}$

F. Krzyzewski et al., J. Cryst. Growth 457 (2017) 38

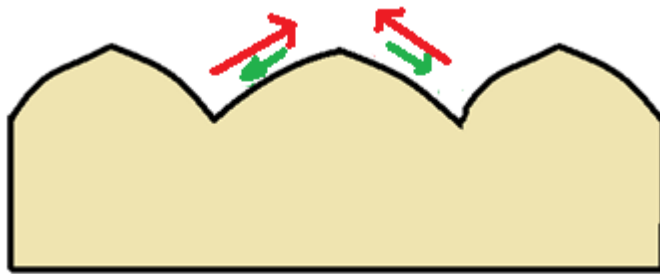
Subsequent layers - mounds

AFM image of a nonideal synthetic dolomite from the Mg:Ca = 1.0 experiment showing mound nanotopography.

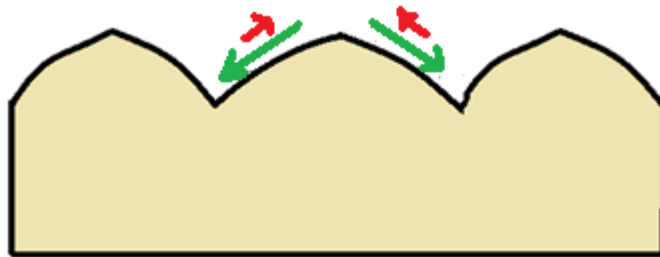


S.E. Kaczmarek & D.F. Sibley,
Journal of Sedimentary Research, 77 (2007) 424

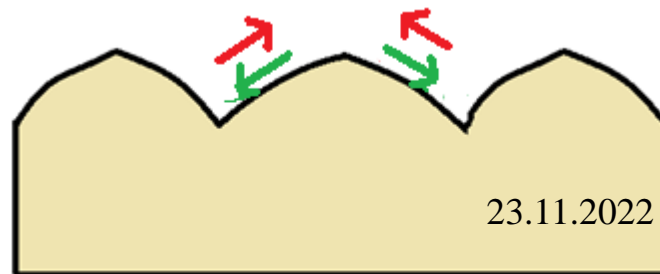
Surface – flux connection



Unstable – growth of the mounds



Stable flat surface – mounds disappearing

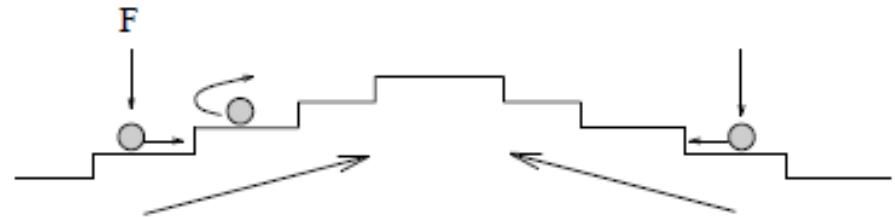


Stable mounds

Surface dynamics – mounds growth

- Flat surface growth :

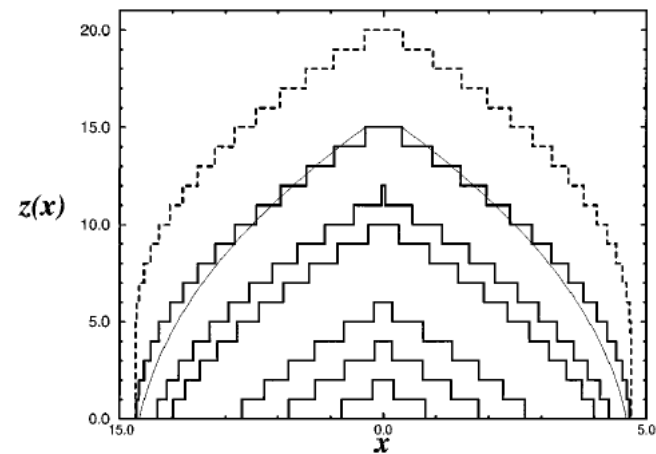
Mounds growth – monostep motion



$$\frac{d\theta_n}{dt} = F (\theta_{n-1} - \theta_n)$$

$$\theta_n = 1 - e^{-\Theta} \sum_{j=0}^{n-1} \frac{\Theta^j}{j!}$$

$$\Theta = \sum_{j=0}^{\infty} \theta_j = Ft$$



**P. Politi & J. Villain,
Phys. Rev. B 54 (1996) 5114**

Literature

- ***H. Omi, T. Ogino, Thin Solid Films 380 (2000) 15***
- ***S. Krukowski, & F. Rosenberger, Phys. Rev. B 49 (1994) 12 464***
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- ***S. Krukowski, et al., Cryst. Res. Technol. 42 (2007) 1281***
- ***M. Załuska-Kotur et al., J. Appl. Phys. 109 (2011) 023515***
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- ***J. Hassan et al., J. Cryst. Growth 310 (2008) 4430***
- ***J. Krug, Physica A 313 (2002) 47***
- ***F. Krzyzewski et al., J. Cryst. Growth 457 (2017) 38***
- ***S.E. Kaczmarek & D.F. Sibley, J.oSediment. Res., 77 (2007) 424***
- ***P. Politi & J. Villain, Phys. Rev. B 54 (1996) 5114***
- ***S. Krukowski et al., Prog. Cryst. Growth Char. Mater. 68 (2022) 100581***